

Datasheet V2020.A.1

G4S12020BM

1200V/20A Silicon Carbide Power Schottky Barrier Diode

Features

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

Benefits

- •AEC-Q101 Qualified
- •Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements
- •Support PPAP
- •Halorn-Free, RoHS compliant, REACH Qualified

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

| Key Characteristics | | | | |
|---|-------|----|--|--|
| V _{RRM} | 1200 | | | |
| I _{F,} T c≪154°C | 10* | Α | | |
| Q _c | 54.4* | nC | | |



| Part No. | Package Type | Marking |
|------------|--------------|------------|
| G4S12020BM | TO-247AB | G4S12020BM |

*Per leg; **Per device

Maximum Ratings

| Parameter | Symbol | Test Condition | Value | Unit | |
|------------------------------------|------------------|---|--------------|--------|--|
| Repetitive Peak Reverse Voltage | V _{RRM} | | 1200 | V | |
| Surge Peak Reverse Voltage | V _{RSM} | | 1200 | V | |
| DC Blocking Voltage | V _{DC} | | 1200 | V | |
| Continuous Forward | | T _C =25℃ | 33.2* | | |
| | I _F | Tc =125 ℃ | 18* | А | |
| Current | | Tc=154℃ | 10* | | |
| Repetitive Peak Forward | I | $T_c=25^{\circ}C$, tp=10ms, Half Sine | 50* | А | |
| Surge Current | I _{FRM} | Wave, D=0.3 | 50 | | |
| Non-repetitive Peak | | $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$, tp=10ms , Half Sine | 140* | А | |
| Forward Surge Current | I _{FSM} | Wave | 140 | | |
| Power Dissipation | D . | Tc=25℃ | 188* | W | |
| | P _{TOT} | Tc=110℃ | 81* | W | |
| Operating Junction | Tj | | -55℃ to 175℃ | °C | |
| Storage Temperature | T _{stg} | | -55℃ to 175℃ | °C | |
| NA | | M3 Screw | 1 | Nm | |
| Mounting Torque | | 6-32 Screw | 8.8 | lbf-in | |

Thermal Characteristic

| Daramatar | Sumbol | Test Condition | Value | Unit |
|-------------------------|------------|----------------|-------|-------------|
| Parameter | Symbol | lest condition | Тур. | Unit |
| Thermal resistance from | р | | 0.8* | <u>с ли</u> |
| junction to case | R_{thJC} | | 0.4** | °C/W |

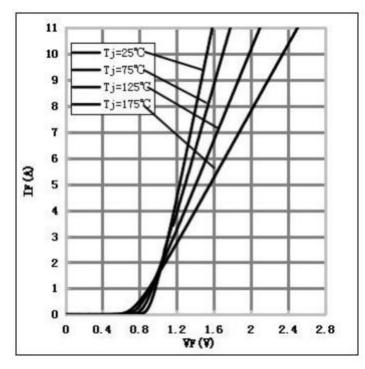
*Per leg; **Per device

| Devenueter | Gumbal | Test Conditions | Numerical | | 11 |
|-------------------------|----------------|----------------------------------|-----------|------|------|
| Parameter | Symbol | Test Conditions | Тур. | Max. | Unit |
| | | $I_F=10A, T_j=25^{\circ}C$ | 1.55 | 1.6 | N/ |
| Forward Voltage | VF | $I_F=10A, T_j=175^{\circ}C$ | 2.35 | 2.5 | V |
| Devenue Comment | | $V_R=1200V, T_j=25^{\circ}C$ | 0.7 | 30 | |
| Reverse Current | I _R | $V_R=1200V, T_j=175$ °C | 3 | 50 | μΑ |
| | | $V_R=800V, T_j=150^{\circ}C$ | | | |
| Total Capacitive Charge | Q _C | $Qc = \int_0^{VR} C(V)dV$ | 54.4 | - | nC |
| | _ | $V_R=0V, T_j=25$ °C, f=1MHZ | 765 | 790 | |
| Total Capacitance | C | V_R =400V, T_j =25°C, f=1MHZ | 50 | 54 | pF |
| | | V_R =800V, T_j =25°C, f=1MHZ | 48.5 | 51 | |

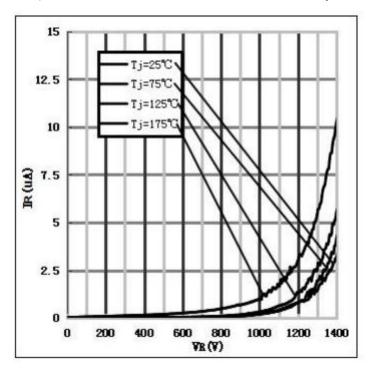
Electrical Characteristics (Per leg)

Performance Graphs (Per leg)

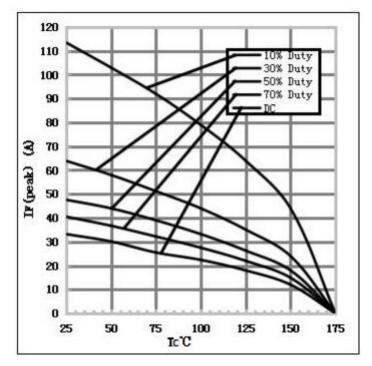
1) Forward IV characteristics as a function of Tj :



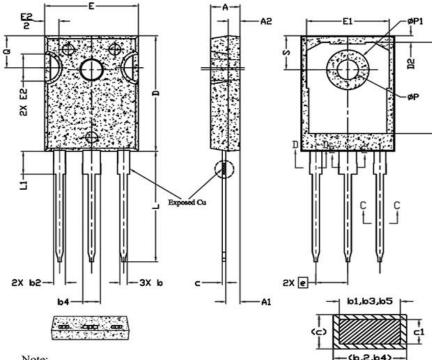
2) Reverse IV characteristics as a function of Tj :



3) Current Derating:



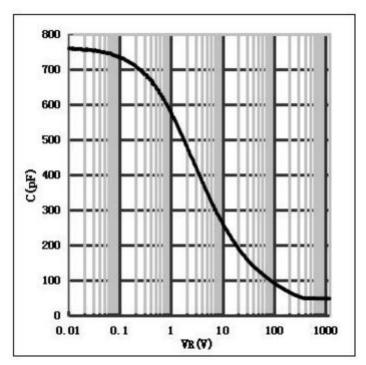
Package TO-247AB



Note:

- 1. Package Reference: JEDEC TO247, Variation AD.
- All Dimensions Are In mm.
 Slot Required, Notch May Be Rounded
- 4. Dimension D & E Do Not Include Mold Flash. Mold Flash Shall Not Exceed 0.127mm Pre Side. These Dimensions Are Measured At The Outermost Extreme Of The Plastic Body.
- 5. Thermal Pad Contour Optional Within Dimension D1 & E1.
- 6. Lead Finish Uncontrolled In L1.
- 7. ØP To Have A Maximum Draft Angle Of 1.5° To The Top Of The Part With A Maximum Hole Diameter Of 3.91mm.
- 8. Dimension "b2" And "b4" Does Not Include Dambar Protrusion.
- Allowable Dambar Protrusion Shall Be 0.10mm Total In Excess Of "b2" And "b4" Dimension At Maximum Material Condition.

4) Capacitance vs. reverse voltage:



| : mm | | | | |
|-------|---------|----------|-------|--------|
| NOTES | 5 | SYMBOL | | |
| | MAX. | NOM. | MIN. | STMBOL |
| | 5.21 | 5.02 | 4.83 | Α |
| | 2.55 | 2.41 | 2.29 | A1 |
| | 2.49 | 2.00 | 1.50 | A2 |
| | 1.33 | 1.20 | 1.12 | b |
| | 1,28 | 1,20 | 1.12 | b1 |
| 6 | 2.39 | 2.00 | 1.91 | b2 |
| | 2,34 | 2,00 | 1,91 | b3 |
| 6,8 | 3.22 | 3.00 | 2.87 | b4 |
| | 3.18 | 3.00 | 2.87 | b5 |
| 6 | 0.69 | 0.60 | 0.55 | c |
| | 0.65 | 0.60 | 0.55 | c1 |
| 4 | 21.10 | 20.95 | 20.80 | D |
| 5 | 17.65 | 16.55 | 16.25 | D1 |
| | 1.35 | 1.19 | 0.51 | D2 |
| 4 | 16.13 | 15.94 | 15.75 | E |
| 5 | 14.16 | 14.02 | 13.46 | E1 |
| 3 | 5.49 | 4.91 | 4.32 | E2 |
| | 5.44BSC | | | e |
| | 20.32 | 20.07 | 19.81 | L |
| 6 | 4.40 | 4.19 | 4.10 | L1 |
| 7 | 3.65 | 3.61 | 3.56 | ØP |
| | | 7.19REF. | | ØP1 |
| | 6.20 | 5.79 | 5.39 | Q |
| | 6.30 | 6,17 | 6.04 | s |

Section C--C,D--D,E--E

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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